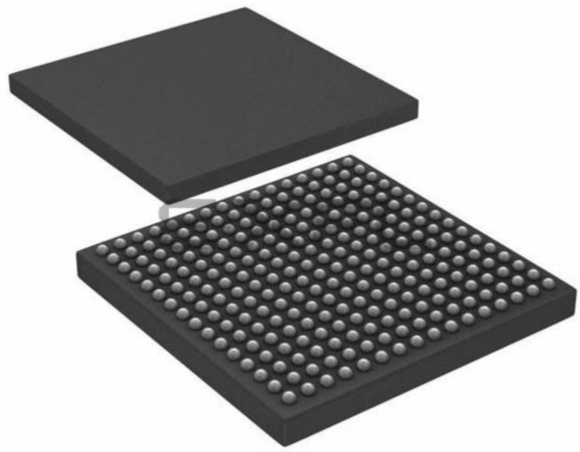

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	36864
Number of I/O	114
Number of Gates	250000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/afs250-2fg256

Related Documents

Datasheet

Core8051

www.microsemi.com/soc/ipdocs/Core8051_DS.pdf

Application Notes

Fusion FlashROM

http://www.microsemi.com/soc/documents/Fusion_FROM_AN.pdf

Fusion SRAM/FIFO Blocks

http://www.microsemi.com/soc/documents/Fusion_RAM_FIFO_AN.pdf

Using DDR in Fusion Devices

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129938

Fusion Security

http://www.microsemi.com/soc/documents/Fusion_Security_AN.pdf

Using Fusion RAM as Multipliers

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Handbook

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Designer User Guide

http://www.microsemi.com/soc/documents/designer_UG.pdf

Fusion FPGA Fabric User Guide

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130817

IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide

http://www.microsemi.com/soc/documents/pa3_libguide_ug.pdf

SmartGen, FlashROM, Flash Memory System Builder, and Analog System Builder User Guide

http://www.microsemi.com/soc/documents/genguide_ug.pdf

White Papers

Fusion Technology

http://www.microsemi.com/soc/documents/Fusion_Tech_WP.pdf

Global Resource Characteristics

AFS600 VersaNet Topology

Clock delays are device-specific. Figure 2-15 is an example of a global tree used for clock routing. The global tree presented in Figure 2-15 is driven by a CCC located on the west side of the AFS600 device. It is used to drive all D-flip-flops in the device.

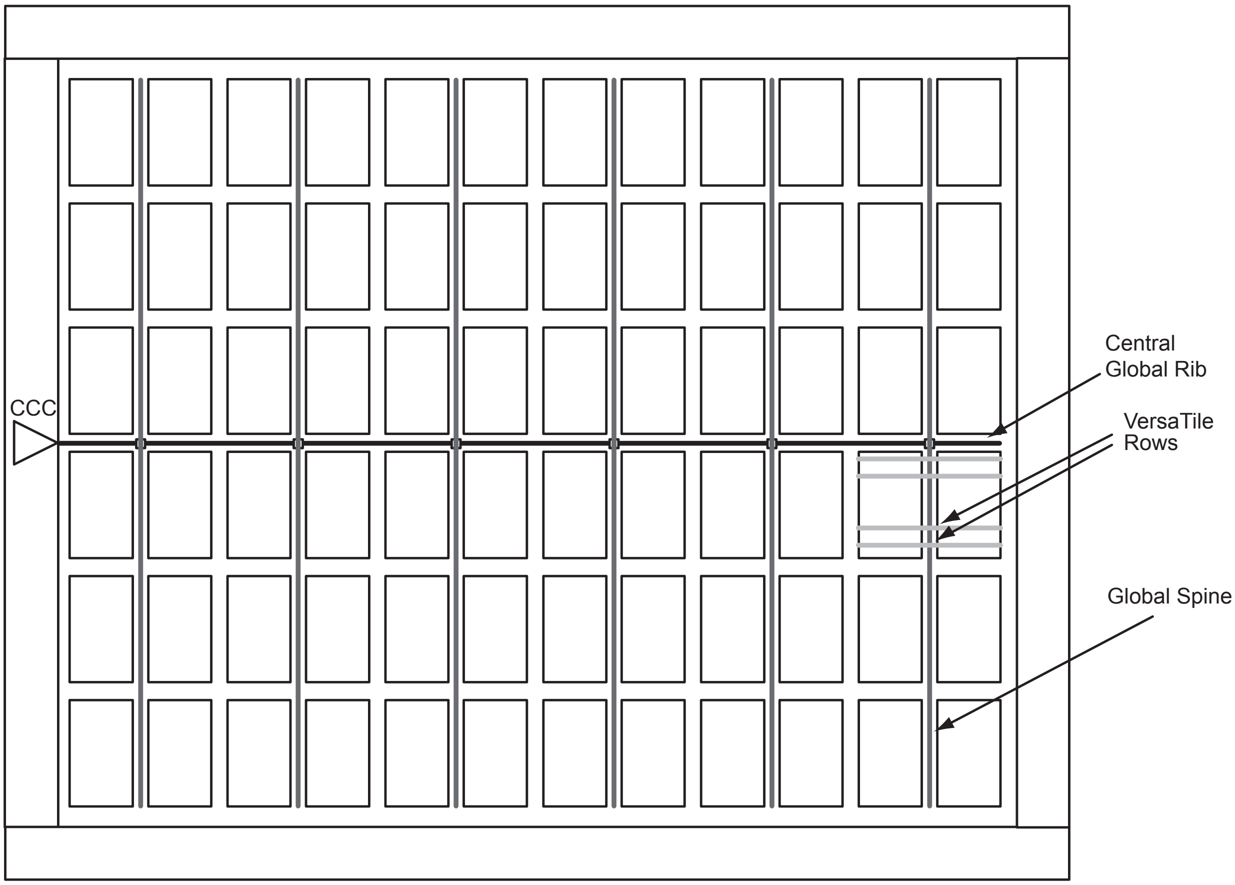


Figure 2-15 • **Example of Global Tree Use in an AFS600 Device for Clock Routing**

Global Buffers with No Programmable Delays

The CLKBUF and CLKBUF_LVPECL/LVDS macros are composite macros that include an I/O macro driving a global buffer, hardwired together (Figure 2-20).

The CLKINT macro provides a global buffer function driven by the FPGA core.

The CLKBUF, CLKBUF_LVPECL/LVDS, and CLKINT macros are pass-through clock sources and do not use the PLL or provide any programmable delay functionality.

Many specific CLKBUF macros support the wide variety of single-ended and differential I/O standards supported by Fusion devices. The available CLKBUF macros are described in the *IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide*.

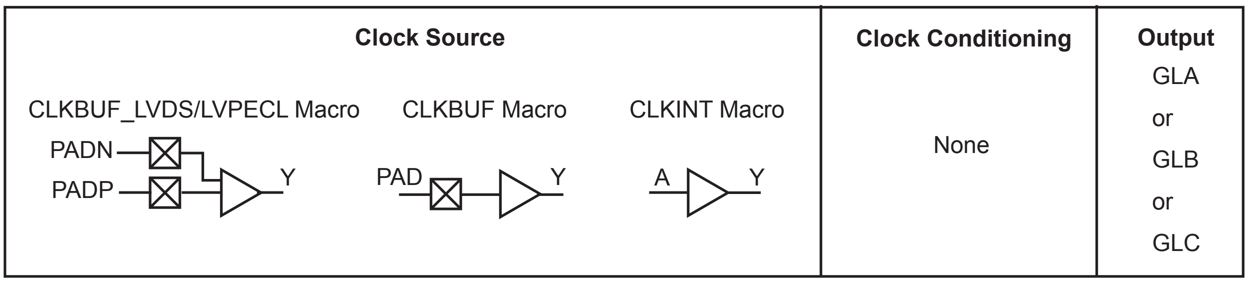


Figure 2-20 **• Global Buffers with No Programmable Delay**

Global Buffers with Programmable Delay

The CLKDLY macro is a pass-through clock source that does not use the PLL, but provides the ability to delay the clock input using a programmable delay (Figure 2-21 on page 2-25). The CLKDLY macro takes the selected clock input and adds a user-defined delay element. This macro generates an output clock phase shift from the input clock.

The CLKDLY macro can be driven by an INBUF macro to create a composite macro, where the I/O macro drives the global buffer (with programmable delay) using a hardwired connection. In this case, the I/O must be placed in one of the dedicated global I/O locations.

Many specific INBUF macros support the wide variety of single-ended and differential I/O standards supported by the Fusion family. The available INBUF macros are described in the *IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide.*

The CLKDLY macro can be driven directly from the FPGA core.

The CLKDLY macro can also be driven from an I/O that is routed through the FPGA regular routing fabric. In this case, users must instantiate a special macro, PLLINT, to differentiate from the hardwired I/O connection described earlier.

The visual CLKDLY configuration in the SmartGen part of the Libero SoC and Designer tools allows the user to select the desired amount of delay and configures the delay elements appropriately. SmartGen also allows the user to select the input clock source. SmartGen will automatically instantiate the special macro, PLLINT, when needed.

Real-Time Counter System

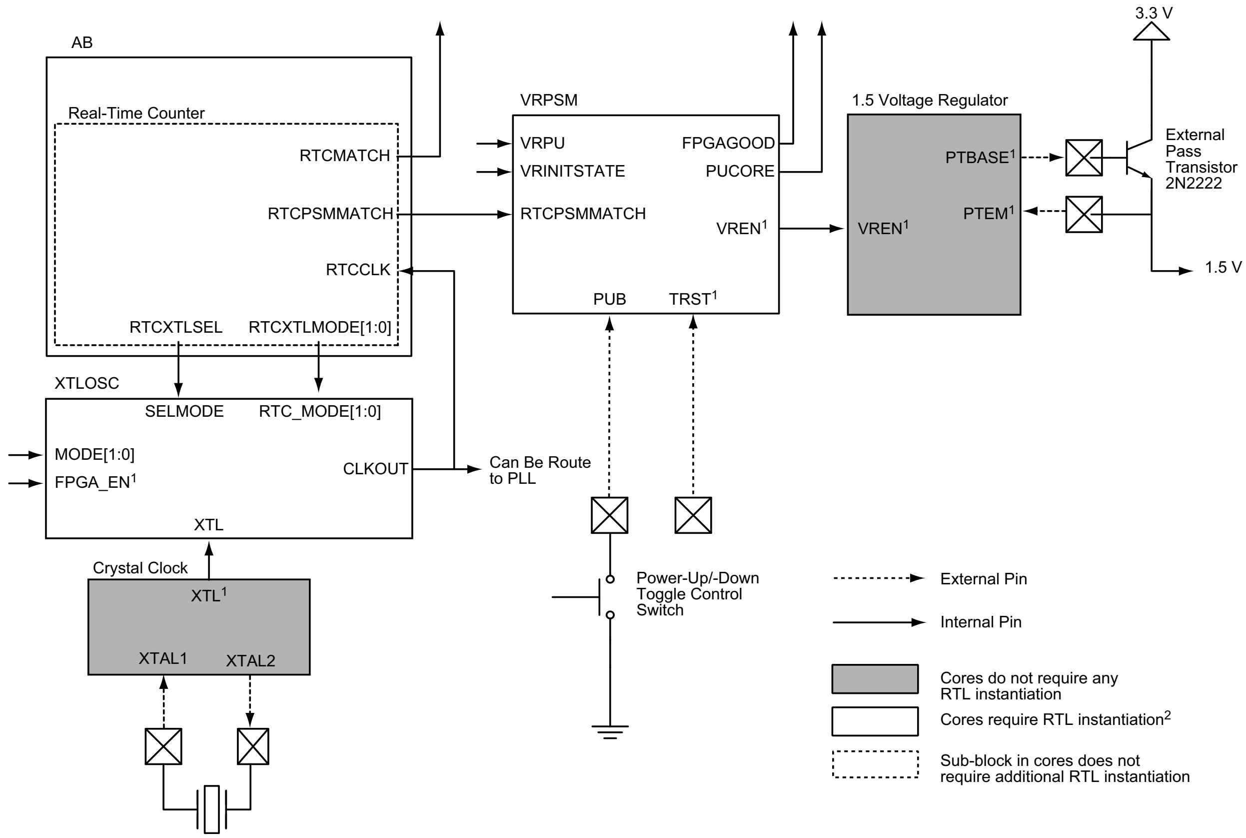
The RTC system enables Fusion devices to support standby and sleep modes of operation to reduce power consumption in many applications.

- Sleep mode, typical 10 µA
- Standby mode (RTC running), typical 3 mA with 20 MHz

The RTC system is composed of five cores:

- RTC sub-block inside Analog Block (AB)
- Voltage Regulator and Power System Monitor (VRPSM)
- Crystal oscillator (XTLOSC); refer to the "Crystal Oscillator" section in the Fusion Clock Resources chapter of the *Fusion FPGA Fabric User Guide* for more detail.
- Crystal clock; does not require instantiation in RTL
- 1.5 V voltage regulator; does not require instantiation in RTL

All cores are powered by 3.3 V supplies, so the RTC system is operational without a 1.5 V supply during standby mode. Figure 2-27 shows their connection.



Notes:

1. *Signals are hardwired internally and do not exist in the macro core.*
2. *User is only required to instantiate the VRPSM macro if the user wishes to specify PUPO behavior of the voltage regulator to be different from the default, or employ user logic to shut the voltage regulator off.*

Figure 2-27 • **Real-Time Counter System (not all the signals are shown for the AB macro)**

Data operations are performed in widths of 1 to 4 bytes. A write to a location in a page that is not already in the Page Buffer will cause the page to be read from the FB Array and stored in the Page Buffer. The block that was addressed during the write will be put into the Block Buffer, and the data written by WD will overwrite the data in the Block Buffer. After the data is written to the Block Buffer, the Block Buffer is then written to the Page Buffer to keep both buffers in sync. Subsequent writes to the same block will overwrite the Block Buffer and the Page Buffer. A write to another block in the page will cause the addressed block to be loaded from the Page Buffer, and the write will be performed as described previously.

The data width can be selected dynamically via the DATAWIDTH input bus. The truth table for the data width settings is detailed in Table 2-21. The minimum resolvable address is one 8-bit byte. For data widths greater than 8 bits, the corresponding address bits are ignored—when DATAWIDTH = 0 (2 bytes), ADDR[0] is ignored, and when DATAWIDTH = '10' or '11' (4 bytes), ADDR[1:0] are ignored. Data pins are LSB-oriented and unused WD data pins must be grounded.

***Table 2-21* • Data Width Settings**

DATAWIDTH[1:0]	Data Width
00	1 byte [7:0]
01	2 byte [15:0]
10, 11	4 bytes [31:0]

Flash Memory Block Protection

Page Loss Protection

When the PAGELOSSPROTECT pin is set to logic 1, it prevents writes to any page other than the current page in the Page Buffer until the page is either discarded or programmed.

A write to another page while the current page is Page Loss Protected will return a STATUS of '11'.

Overwrite Protection

Any page that is Overwrite Protected will result in the STATUS being set to '01' when an attempt is made to either write, program, or erase it. To set the Overwrite Protection state for a page, set the OVERWRITEPROTECT pin when a Program operation is undertaken. To clear the Overwrite Protect state for a given page, an Unprotect Page operation must be performed on the page, and then the page must be programmed with the OVERWRITEPROTECT pin cleared to save the new page.

LOCKREQUEST

The LOCKREQUEST signal is used to give the user interface control over simultaneous access of the FB from both the User and JTAG interfaces. When LOCKREQUEST is asserted, the JTAG interface will hold off any access attempts until LOCKREQUEST is deasserted.

Flash Memory Block Operations

FB Operation Priority

The FB provides for priority of operations when multiple actions are requested simultaneously. Table 2-22 shows the priority order (priority 0 is the highest).

***Table 2-22* • FB Operation Priority**

Operation	Priority
System Initialization	0
FB Reset	1
Read	2
Write	3
Erase Page	4
Program	5
Unprotect Page	6
Discard Page	7

***Table 2-36* • Analog Block Pin Description (continued)**

Signal Name	Number of Bits	Direction	Function	Location of Details
GDON0 to GDON9	10	Input	Control to power MOS – 1 per quad	Analog Quad
TMSTB0 to TMSTB9	10	Input	Temperature monitor strobe – 1 per quad; active high	Analog Quad
DAVOUT0, DACOUT0, DATOUT0 to DAVOUT9, DACOUT9, DATOUT9	30	Output	Digital outputs – 3 per quad	Analog Quad
DENAV0, DENAC0, DENAT0 to DENAV9, DENAC9, DENAT9	30	Input	Digital input enables – 3 per quad	Analog Quad
AV0	1	Input	Analog Quad 0	Analog Quad
AC0	1	Input		Analog Quad
AG0	1	Output		Analog Quad
AT0	1	Input		Analog Quad
ATRETURN01	1	Input	Temperature monitor return shared by Analog Quads 0 and 1	Analog Quad
AV1	1	Input	Analog Quad 1	Analog Quad
AC1	1	Input		Analog Quad
AG1	1	Output		Analog Quad
AT1	1	Input		Analog Quad
AV2	1	Input	Analog Quad 2	Analog Quad
AC2	1	Input		Analog Quad
AG2	1	Output		Analog Quad
AT2	1	Input		Analog Quad
ATRETURN23	1	Input	Temperature monitor return shared by Analog Quads 2 and 3	Analog Quad
AV3	1	Input	Analog Quad 3	Analog Quad
AC3	1	Input		Analog Quad
AG3	1	Output		Analog Quad
AT3	1	Input		Analog Quad
AV4	1	Input	Analog Quad 4	Analog Quad
AC4	1	Input		Analog Quad
AG4	1	Output		Analog Quad
AT4	1	Input		Analog Quad
ATRETURN45	1	Input	Temperature monitor return shared by Analog Quads 4 and 5	Analog Quad
AV5	1	Input	Analog Quad 5	Analog Quad
AC5	1	Input		Analog Quad
AG5	1	Output		Analog Quad
AT5	1	Input		Analog Quad
AV6	1	Input	Analog Quad 6	Analog Quad
AC6	1	Input		Analog Quad

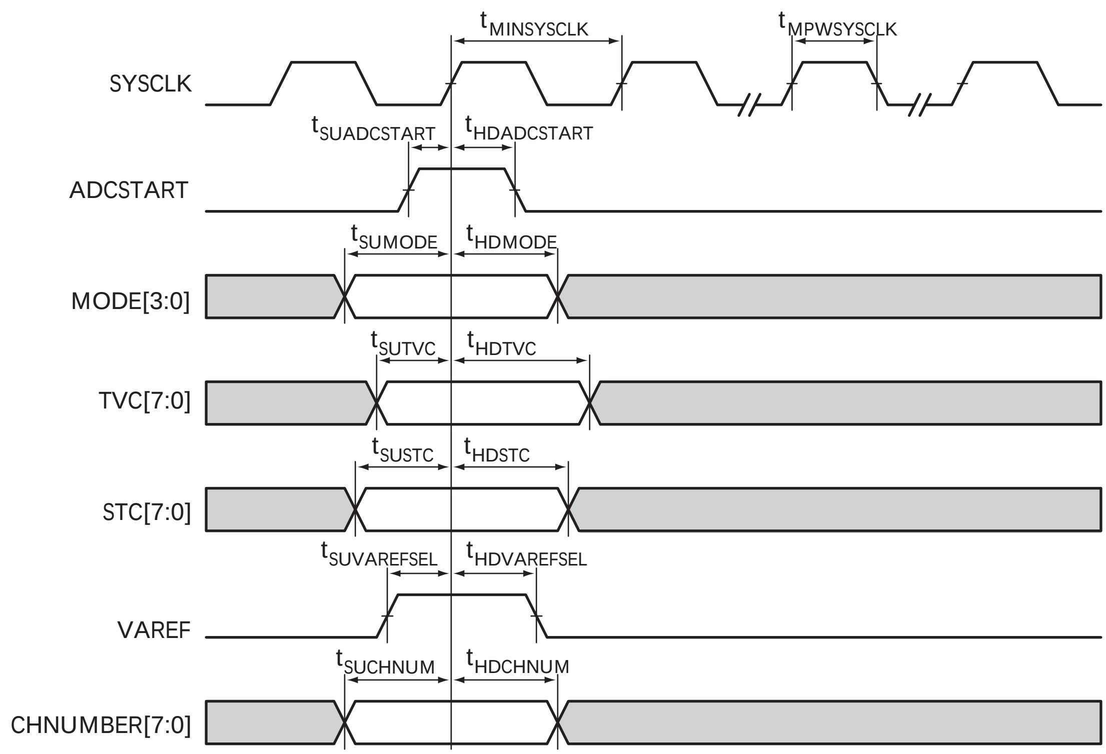
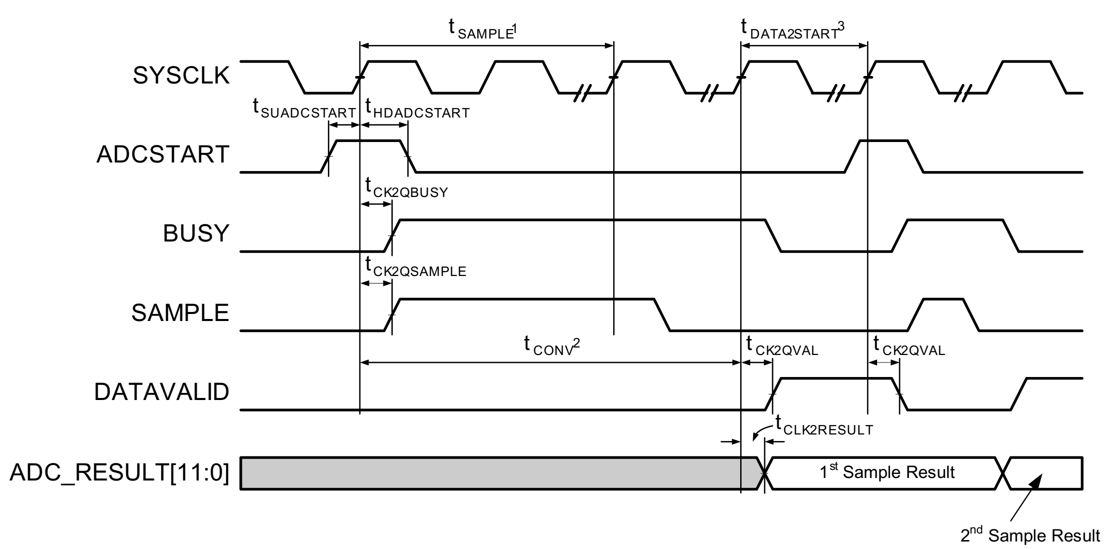


Figure 2-90 **• Input Setup Time**

Standard Conversion



Notes:

1. *Refer to EQ 20 on page 2-109 for the calculation on the sample time, t_{SAMPLE}.*
2. *See EQ 23 on page 2-109 for calculation of the conversion time, t_{CONV}.*
3. *Minimum time to issue an ADCSTART after DATAVALID is 1 SYSCLK period*

Figure 2-91 **• Standard Conversion Status Signal Timing Diagram**

Table 2-52 • **Calibrated Analog Channel Accuracy [1,2,3]**
Worst-Case Industrial Conditions, T_J = 85°C

		Condition	Total Channel Error (LSB)		
Analog Pad	**Prescaler Range (V)**	**Input Voltage[4] (V)**	**Negative Max.**	**Median**	**Positive Max.**
Positive Range			**ADC in 10-Bit Mode**		
AV, AC	16	0.300 to 12.0	–6	1	6
	8	0.250 to 8.00	–6	0	6
	4	0.200 to 4.00	–7	–1	7
	2	0.150 to 2.00	–7	0	7
	1	0.050 to 1.00	–6	–1	6
AT	16	0.300 to 16.0	–5	0	5
	4	0.100 to 4.00	–7	–1	7
Negative Range			**ADC in 10-Bit Mode**		
AV, AC	16	–0.400 to –10.5	–7	1	9
	8	–0.350 to –8.00	–7	–1	7
	4	–0.300 to –4.00	–7	–2	9
	2	–0.250 to –2.00	–7	–2	7
	1	–0.050 to –1.00	–16	–1	20

Notes:

1. *Channel Accuracy includes prescaler and ADC accuracies. For 12-bit mode, multiply the LSB count by 4. For 8-bit mode, divide the LSB count by 4. Overall accuracy remains the same.*
2. *Requires enabling Analog Calibration using SmartGen Analog System Builder. For further details, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.*
3. *Calibrated with two-point calibration methodology, using 20% and 80% full-scale points.*
4. *The lower limit of the input voltage is determined by the prescaler input offset.*

5 V Output Tolerance

Fusion I/Os must be set to 3.3 V LVTTL or 3.3 V LVCMOS mode to reliably drive 5 V TTL receivers. It is also critical that there be NO external I/O pull-up resistor to 5 V, since this resistor would pull the I/O pad voltage beyond the 3.6 V absolute maximum value and consequently cause damage to the I/O.

When set to 3.3 V LVTTL or 3.3 V LVCMOS mode, Fusion I/Os can directly drive signals into 5 V TTL receivers. In fact, VOL = 0.4 V and VOH = 2.4 V in both 3.3 V LVTTL and 3.3 V LVCMOS modes exceed the VIL = 0.8 V and VIH = 2 V level requirements of 5 V TTL receivers. Therefore, level '1' and level '0' will be recognized correctly by 5 V TTL receivers.

Simultaneously Switching Outputs and PCB Layout

- Simultaneously switching outputs (SSOs) can produce signal integrity problems on adjacent signals that are not part of the SSO bus. Both inductive and capacitive coupling parasitics of bond wires inside packages and of traces on PCBs will transfer noise from SSO busses onto signals adjacent to those busses. Additionally, SSOs can produce ground bounce noise and VCCI dip noise. These two noise types are caused by rapidly changing currents through GND and VCCI package pin inductances during switching activities:
- Ground bounce noise voltage = L(GND) * di/dt
- VCCI dip noise voltage = L(VCCI) * di/dt

Any group of four or more input pins switching on the same clock edge is considered an SSO bus. The shielding should be done both on the board and inside the package unless otherwise described.

In-package shielding can be achieved in several ways; the required shielding will vary depending on whether pins next to SSO bus are LVTTL/LVCMOS inputs, LVTTL/LVCMOS outputs, or GTL/SSTL/HSTL/LVDS/LVPECL inputs and outputs. Board traces in the vicinity of the SSO bus have to be adequately shielded from mutual coupling and inductive noise that can be generated by the SSO bus. Also, noise generated by the SSO bus needs to be reduced inside the package.

PCBs perform an important function in feeding stable supply voltages to the IC and, at the same time, maintaining signal integrity between devices.

Key issues that need to considered are as follows:

- Power and ground plane design and decoupling network design
- Transmission line reflections and terminations

Selectable Skew between Output Buffer Enable/Disable Time

The configurable skew block is used to delay the output buffer assertion (enable) without affecting deassertion (disable) time.

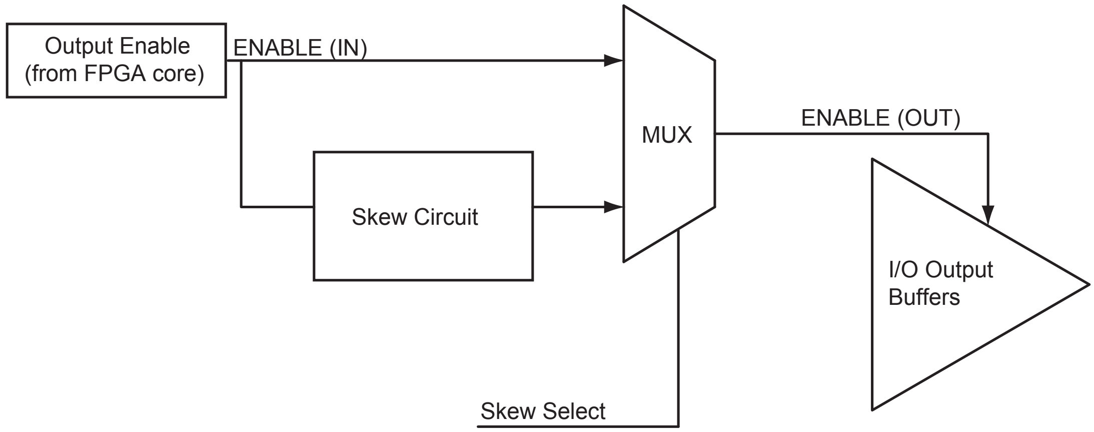


Figure 2-107 **• Block Diagram of Output Enable Path**

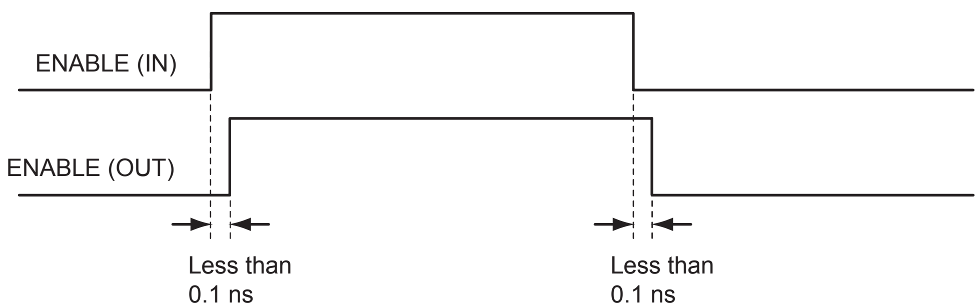


Figure 2-108 **• Timing Diagram (option1: bypasses skew circuit)**

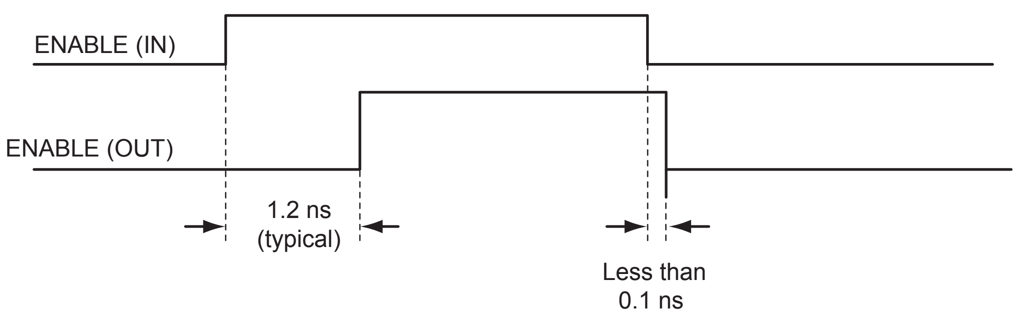


Figure 2-109 **• Timing Diagram (option 2: enables skew circuit)**

Table 2-78 • **Fusion Standard I/O Standards—OUT_DRIVE Settings**

I/O Standards	OUT_DRIVE (mA)					
	2	4	6	8	Slew	
LVTTL/LVCMOS 3.3 V	3	3	3	3	High	Low
LVCMOS 2.5 V	3	3	3	3	High	Low
LVCMOS 1.8 V	3	3	–	–	High	Low
LVCMOS 1.5 V	3	–	–	–	High	Low

Table 2-79 • **Fusion Advanced I/O Standards—SLEW and OUT_DRIVE Settings**

I/O Standards	OUT_DRIVE (mA)							
	2	4	6	8	12	16	Slew	
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3	High	Low
LVCMOS 2.5 V	3	3	3	3	3	–	High	Low
LVCMOS 1.8 V	3	3	3	3	–	–	High	Low
LVCMOS 1.5 V	3	3	–	–	–	–	High	Low

Table 2-80 • **Fusion Pro I/O Standards—SLEW and OUT_DRIVE Settings**

I/O Standards	OUT_DRIVE (mA)							Slew	
	2	4	6	8	12	16	24		
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3	3	High	Low
LVCMOS 2.5 V	3	3	3	3	3	3	3	High	Low
LVCMOS 2.5 V/5.0 V	3	3	3	3	3	3	3	High	Low
LVCMOS 1.8 V	3	3	3	3	3	3	–	High	Low
LVCMOS 1.5 V	3	3	3	3	3	–	–	High	Low

SSTL3 Class II

Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-165 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class II	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL[1]	IIH[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
21 mA	–0.3	VREF – 0.2	VREF + 0.2	3.6	0.5	VCCI – 0.9	21	21	109	103	10	10

Notes:

1. *IIL is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
3. *Currents are measured at high temperature (100°C junction temperature) and maximum voltage.*
4. *Currents are measured at 85°C junction temperature.*

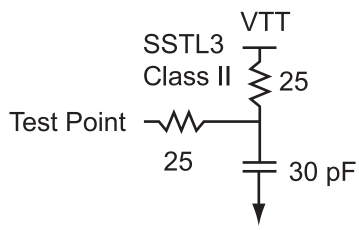


Figure 2-133 • AC Loading

Table 2-166 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C_{LOAD} (pF)
VREF – 0.2	VREF + 0.2	1.5	1.5	1.485	30

*Note: *Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.*

Timing Characteristics

Table 2-167 • SSTL3- Class II
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 1.5 V

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.66	2.07	0.04	1.25	0.43	2.10	1.67			4.34	3.91	ns
–1	0.56	1.76	0.04	1.06	0.36	1.79	1.42			3.69	3.32	ns
–2	0.49	1.54	0.03	0.93	0.32	1.57	1.25			3.24	2.92	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

I/O Register Specifications

Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

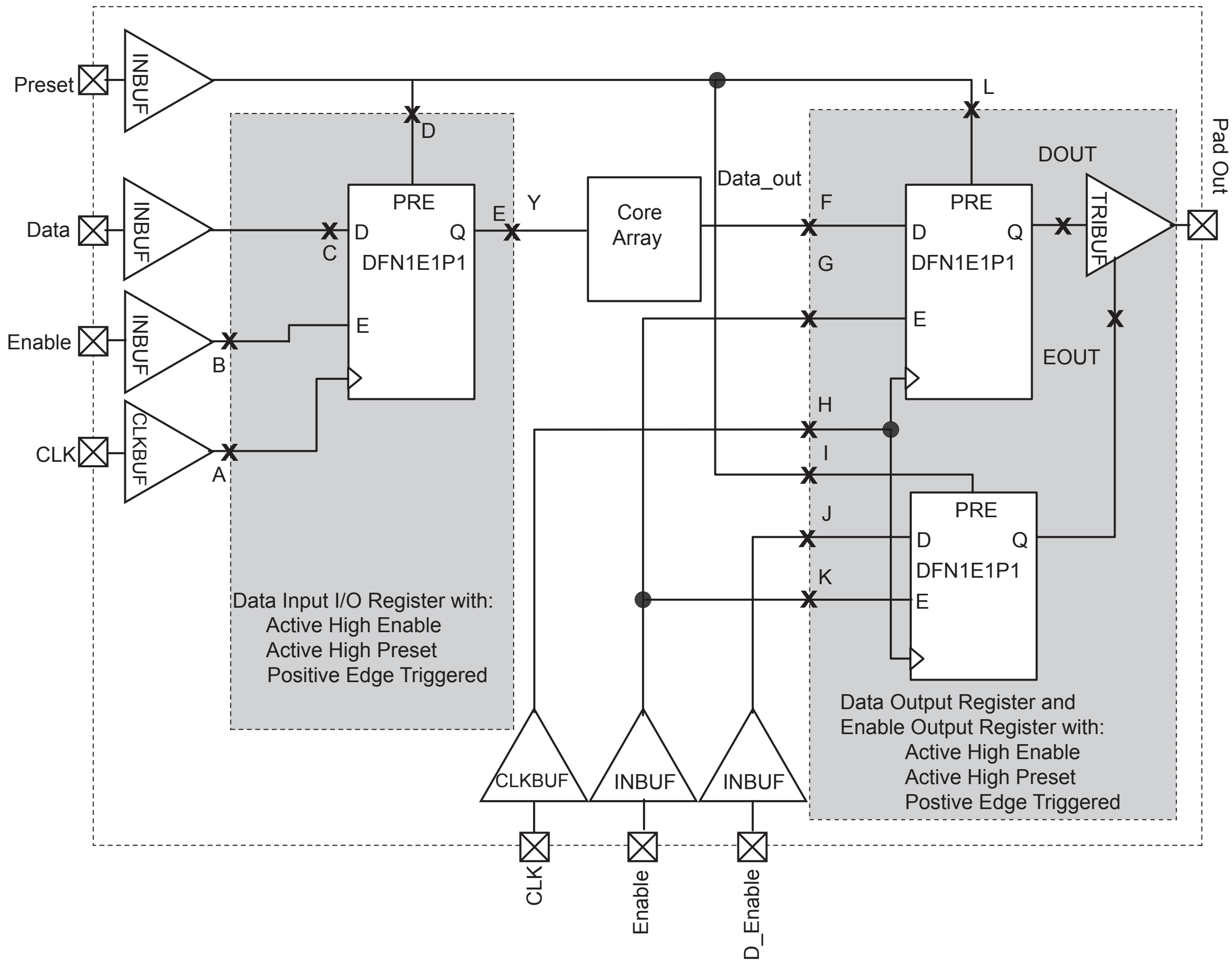


Figure 2-137 • Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

Table 2-174 • **Parameter Definitions and Measuring Nodes**

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t_{OCLKQ}	Clock-to-Q of the Output Data Register	H, DOUT
t_{OSUD}	Data Setup Time for the Output Data Register	F, H
t_{OHD}	Data Hold Time for the Output Data Register	F, H
t_{OSUE}	Enable Setup Time for the Output Data Register	G, H
t_{OHE}	Enable Hold Time for the Output Data Register	G, H
t_{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	L,DOUT
$t_{OREMPRE}$	Asynchronous Preset Removal Time for the Output Data Register	L, H
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Data Register	L, H
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	H, EOUT
t_{OESUD}	Data Setup Time for the Output Enable Register	J, H
t_{OEHD}	Data Hold Time for the Output Enable Register	J, H
t_{OESUE}	Enable Setup Time for the Output Enable Register	K, H
t_{OEHE}	Enable Hold Time for the Output Enable Register	K, H
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	I, H
$t_{OERECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	I, H
t_{ICLKQ}	Clock-to-Q of the Input Data Register	A, E
t_{ISUD}	Data Setup Time for the Input Data Register	C, A
t_{IHD}	Data Hold Time for the Input Data Register	C, A
t_{ISUE}	Enable Setup Time for the Input Data Register	B, A
t_{IHE}	Enable Hold Time for the Input Data Register	B, A
t_{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	D, E
$t_{IREMPRE}$	Asynchronous Preset Removal Time for the Input Data Register	D, A
$t_{IRECPRE}$	Asynchronous Preset Recovery Time for the Input Data Register	D, A

Note: *See Figure 2-137 on page 2-212 for more information.

Table 3-9 • **AFS600 Quiescent Supply Current Characteristics**

Parameter	Description	Conditions	Temp.	Min	Typ	Max	Unit
ICC[1]	1.5 V quiescent current	Operational standby[4], VCC = 1.575 V	T_J = 25°C		13	25	mA
			T_J = 85°C		20	45	mA
			T_J=100°C		25	75	mA
		Standby mode[5] or Sleep mode[6], VCC = 0 V			0	0	µA
ICC33[2]	3.3 V analog supplies current	Operational standby[4], VCC33 = 3.63 V	T_J = 25°C		9.8	13	mA
			T_J = 85°C		10.7	14	mA
			T_J = 100°C		10.8	15	mA
		Operational standby, only Analog Quad and –3.3 V output ON, VCC33 = 3.63 V	T_J = 25°C		0.31	2	mA
			T_J = 85°C		0.35	2	mA
			T_J = 100°C		0.45	2	mA
		Standby mode[5], VCC33 = 3.63 V	T_J = 25°C		2.8	3.6	mA
			T_J = 85°C		2.9	4	mA
			T_J = 100°C		3.5	6	mA
		Sleep mode[6], V_{CC33} = 3.63 V	T_J = 25°C		17	19	µA
			T_J = 85°C		18	20	µA
			T_J = 100°C		24	25	µA
ICCI[3]	I/O quiescent current	Operational standby[4], VCCIx = 3.63 V	T_J = 25°C		417	648	µA
			T_J = 85°C		417	648	µA
			T_J = 100°C		417	649	µA
IJTAG	JTAG I/O quiescent current	Operational standby[4], VJTAG = 3.63 V	T_J = 25°C		80	100	µA
			T_J = 85°C		80	100	µA
			T_J = 100°C		80	100	µA
		Standby mode[5] or Sleep mode[6], VJTAG = 0 V			0	0	µA

Notes:

1. *ICC is the 1.5 V power supplies, ICC and ICC15A.*
2. *ICC33A includes ICC33A, ICC33PMP, and ICCOSC.*
3. *ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.*
4. *Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.*
5. *XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.*
6. *Sleep Mode, VCC = VJTAG = VPUMP = 0 V.*

QN180		
Pin Number	AFS090 Function	AFS250 Function
C21	AG2	AG2
C22	NC	NC
C23	NC	NC
C24	NC	NC
C25	NC	AT5
C26	GNDAQ	GNDAQ
C27	NC	NC
C28	NC	NC
C29	NC	NC
C30	NC	NC
C31	GND	GND
C32	NC	NC
C33	NC	NC
C34	NC	NC
C35	GND	GND
C36	GDB0/IO39NPB1V0	GDA0/IO54NPB1V0
C37	GDA1/IO37NSB1V0	GDC0/IO52NSB1V0
C38	GCA0/IO36NDB1V0	GCA0/IO49NDB1V0
C39	GCB1/IO35PPB1V0	GCB1/IO48PPB1V0
C40	GND	GND
C41	GCA2/IO32NPB1V0	IO41NPB1V0
C42	GBB2/IO31NDB1V0	IO40NDB1V0
C43	NC	NC
C44	NC	GBA1/IO39RSB0V0
C45	NC	GBB0/IO36RSB0V0
C46	GND	GND
C47	NC	IO30RSB0V0
C48	IO22RSB0V0	IO27RSB0V0
C49	GND	GND
C50	IO13RSB0V0	IO16RSB0V0
C51	IO09RSB0V0	IO12RSB0V0
C52	IO06RSB0V0	IO09RSB0V0
C53	GND	GND
C54	NC	GAB1/IO03RSB0V0
C55	NC	GAA0/IO00RSB0V0
C56	NC	NC

QN180		
Pin Number	AFS090 Function	AFS250 Function
D1	NC	NC
D2	NC	NC
D3	NC	NC
D4	NC	NC

PQ208		
Pin Number	AFS250 Function	AFS600 Function
74	AV2	AV4
75	AC2	AC4
76	AG2	AG4
77	AT2	AT4
78	ATRTN1	ATRTN2
79	AT3	AT5
80	AG3	AG5
81	AC3	AC5
82	AV3	AV5
83	AV4	AV6
84	AC4	AC6
85	AG4	AG6
86	AT4	AT6
87	ATRTN2	ATRTN3
88	AT5	AT7
89	AG5	AG7
90	AC5	AC7
91	AV5	AV7
92	NC	AV8
93	NC	AC8
94	NC	AG8
95	NC	AT8
96	NC	ATRTN4
97	NC	AT9
98	NC	AG9
99	NC	AC9
100	NC	AV9
101	GNDAQ	GNDAQ
102	VCC33A	VCC33A
103	ADCGNDREF	ADCGNDREF
104	VAREF	VAREF
105	PUB	PUB
106	VCC33A	VCC33A
107	GNDA	GNDA
108	PTEM	PTEM
109	PTBASE	PTBASE
110	GNDNVM	GNDNVM

PQ208		
Pin Number	AFS250 Function	AFS600 Function
111	VCCNVM	VCCNVM
112	VCC	VCC
112	VCC	VCC
113	VPUMP	VPUMP
114	GNDQ	NC
115	VCCIB1	TCK
116	TCK	TDI
117	TDI	TMS
118	TMS	TDO
119	TDO	TRST
120	TRST	VJTAG
121	VJTAG	IO57NDB2V0
122	IO57NDB1V0	GDC2/IO57PDB2V0
123	GDC2/IO57PDB1V0	IO56NDB2V0
124	IO56NDB1V0	GDB2/IO56PDB2V0
125	GDB2/IO56PDB1V0	IO55NDB2V0
126	VCCIB1	GDA2/IO55PDB2V0
127	GND	GDA0/IO54NDB2V0
128	IO55NDB1V0	GDA1/IO54PDB2V0
129	GDA2/IO55PDB1V0	VCCIB2
130	GDA0/IO54NDB1V0	GND
131	GDA1/IO54PDB1V0	VCC
132	GDB0/IO53NDB1V0	GCA0/IO45NDB2V0
133	GDB1/IO53PDB1V0	GCA1/IO45PDB2V0
134	GDC0/IO52NDB1V0	GCB0/IO44NDB2V0
135	GDC1/IO52PDB1V0	GCB1/IO44PDB2V0
136	IO51NSB1V0	GCC0/IO43NDB2V0
137	VCCIB1	GCC1/IO43PDB2V0
138	GND	IO42NDB2V0
139	VCC	IO42PDB2V0
140	IO50NDB1V0	IO41NDB2V0
141	IO50PDB1V0	GCC2/IO41PDB2V0
142	GCA0/IO49NDB1V0	VCCIB2
143	GCA1/IO49PDB1V0	GND
144	GCB0/IO48NDB1V0	VCC
145	GCB1/IO48PDB1V0	IO40NDB2V0
146	GCC0/IO47NDB1V0	GCB2/IO40PDB2V0

FG484		
Pin Number	AFS600 Function	AFS1500 Function
A1	GND	GND
A2	VCC	NC
A3	GAA1/IO01PDB0V0	GAA1/IO01PDB0V0
A4	GAB0/IO02NDB0V0	GAB0/IO02NDB0V0
A5	GAB1/IO02PDB0V0	GAB1/IO02PDB0V0
A6	IO07NDB0V1	IO07NDB0V1
A7	IO07PDB0V1	IO07PDB0V1
A8	IO10PDB0V1	IO09PDB0V1
A9	IO14NDB0V1	IO13NDB0V2
A10	IO14PDB0V1	IO13PDB0V2
A11	IO17PDB1V0	IO24PDB1V0
A12	IO18PDB1V0	IO26PDB1V0
A13	IO19NDB1V0	IO27NDB1V1
A14	IO19PDB1V0	IO27PDB1V1
A15	IO24NDB1V1	IO35NDB1V2
A16	IO24PDB1V1	IO35PDB1V2
A17	GBC0/IO26NDB1V1	GBC0/IO40NDB1V2
A18	GBA0/IO28NDB1V1	GBA0/IO42NDB1V2
A19	IO29NDB1V1	IO43NDB1V2
A20	IO29PDB1V1	IO43PDB1V2
A21	VCC	NC
A22	GND	GND
AA1	VCC	NC
AA2	GND	GND
AA3	VCCIB4	VCCIB4
AA4	VCCIB4	VCCIB4
AA5	PCAP	PCAP
AA6	AG0	AG0
AA7	GNDA	GNDA
AA8	AG1	AG1
AA9	AG2	AG2
AA10	GNDA	GNDA
AA11	AG3	AG3
AA12	AG6	AG6
AA13	GNDA	GNDA

FG484		
Pin Number	AFS600 Function	AFS1500 Function
AA14	AG7	AG7
AA15	AG8	AG8
AA16	GNDA	GNDA
AA17	AG9	AG9
AA18	VAREF	VAREF
AA19	VCCIB2	VCCIB2
AA20	PTEM	PTEM
AA21	GND	GND
AA22	VCC	NC
AB1	GND	GND
AB2	VCC	NC
AB3	NC	IO94NSB4V0
AB4	GND	GND
AB5	VCC33N	VCC33N
AB6	AT0	AT0
AB7	ATRTN0	ATRTN0
AB8	AT1	AT1
AB9	AT2	AT2
AB10	ATRTN1	ATRTN1
AB11	AT3	AT3
AB12	AT6	AT6
AB13	ATRTN3	ATRTN3
AB14	AT7	AT7
AB15	AT8	AT8
AB16	ATRTN4	ATRTN4
AB17	AT9	AT9
AB18	VCC33A	VCC33A
AB19	GND	GND
AB20	NC	IO76NPB2V0
AB21	VCC	NC
AB22	GND	GND
B1	VCC	NC
B2	GND	GND
B3	GAA0/IO01NDB0V0	GAA0/IO01NDB0V0
B4	GND	GND

Revision	Changes	Page
Revision 3 (continued)	The "RC Oscillator" section was revised to correct a sentence that did not differentiate accuracy for commercial and industrial temperature ranges, which is given in Table 2-9 • Electrical Characteristics of RC Oscillator (SAR 33722).	2-19
	Figure 2-57 • FIFO Read and Figure 2-58 • FIFO Write are new (SAR 34840).	2-72
	The first paragraph of the "Offset" section was removed; it was intended to be replaced by the paragraph following it (SAR 22647).	2-95
	IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected in Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions (SAR 39813).	2-164
	The drive strength, IOL, and IOH for 3.3 V GTL and 2.5 V GTL were changed from 25 mA to 20 mA in the following tables (SAR 37373): Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions, Table 2-92 • Summary of I/O Timing Characteristics – Software Default Settings Table 2-96 • I/O Output Buffer Maximum Resistances 1 Table 2-138 • Minimum and Maximum DC Input and Output Levels Table 2-141 • Minimum and Maximum DC Input and Output Levels	 2-164 2-167 2-169 2-199 2-200
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34800): "It uses a 5 V–tolerant input buffer and push-pull output buffer."	2-181
	Corrected the inadvertent error in maximum values for LVPECL VIH and VIL and revised them to "3.6" in Table 2-171 • Minimum and Maximum DC Input and Output Levels, making these consistent with Table 3-1 • Absolute Maximum Ratings, and Table 3-4 • Overshoot and Undershoot Limits 1 (SAR 37687).	2-211
	The maximum frequency for global clock parameter was removed from Table 2-5 • AFS1500 Global Resource Timing through Table 2-8 • AFS090 Global Resource Timing because a frequency on the global is only an indication of what the global network can do. There are other limiters such as the SRAM, I/Os, and PLL. SmartTime software should be used to determine the design frequency (SAR 36955).	2-16 to 2-17
Revision 2 (March 2012)	The phrase "without debug" was removed from the "Soft ARM Cortex-M1 Fusion Devices (M1)" section (SAR 21390).	I
	The "In-System Programming (ISP) and Security" section, "Security" section, "Flash Advantages" section, and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34679).	I, 1-2, 2-228
	The Y security option and Licensed DPA Logo was added to the "Product Ordering Codes" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34721).	III
	The "Specifying I/O States During Programming" section is new (SAR 34693).	1-9
	The following information was added before Figure 2-17 • XTLOSC Macro: In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating (SAR 24119).	2-20
	Table 2-12 • Fusion CCC/PLL Specification was updated. A note was added indicating that when the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available (SAR 34814).	2-28

Revision	Changes	Page
Advance v1.0 (continued)	This change table states that in the "208-Pin PQFP" table listed under the Advance v0.8 changes, the AFS090 device had a pin change. That is incorrect. Pin 102 was updated for AFS250 and AFS600. The function name changed from $V_{CC33ACAP}$ to V_{CC33A}.	3-8
Advance v0.9 (October 2007)	In the "Package I/Os: Single-/Double-Ended (Analog)" table, the AFS1500/M7AFS1500 I/O counts were updated for the following devices: FG484: 223/109 FG676: 252/126	II
	In the "108-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pin: B25	3-2
	In the "180-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: B29 AFS250: B29	3-4
	In the "208-Pin PQFP" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: 102 AFS250: 102	3-8
	In the "256-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: T14 AFS250: T14 AFS600: T14 AFS1500: T14	3-12
Advance v0.9 (continued)	In the "484-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS600: AB18 AFS1500: AB18	3-20
	In the "676-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS1500: AD20	3-28
Advance v0.8 (June 2007)	Figure 2-16 • Fusion Clocking Options and the "RC Oscillator" section were updated to change GND_OSC and VCC_OSC to GNDOSC and VCCOSC.	2-20, 2-21
	Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro was updated to change the positions of OADIVRST and OADIVHALF, and a note was added.	2-25
	The "Crystal Oscillator" section was updated to include information about controlling and enabling/disabling the crystal oscillator.	2-22
	Table 2-11 · Electrical Characteristics of the Crystal Oscillator was updated to change the typical value of $I_{DYNXTAL}$ for 0.032–0.2 MHz to 0.19.	2-24
	The "1.5 V Voltage Regulator" section was updated to add "or floating" in the paragraph stating that an external pull-down is required on TRST to power down the VR.	2-41
	The "1.5 V Voltage Regulator" section was updated to include information on powering down with the VR.	2-41